

**TO-277 Schottky Barrier Rectifier Diode 肖特基势垒整流二极管**

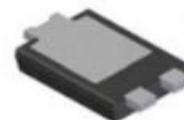
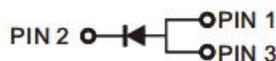
■ **Features 特点**

High surge current capability 高浪涌电流能力

Low forward voltage drop 低正向压降

High reliability 高可靠性

Case 封装:TO-277



■ **Maximum Rating 最大额定值**

( $T_A=25^{\circ}\text{C}$  unless otherwise noted 如无特殊说明, 温度为  $25^{\circ}\text{C}$ )

Characteristic 特性参数	Symbol 符号	Rating 额定值	Unit 单位
Peak Reverse Voltage 反向峰值电压	$V_{RRM}$	100	V
DC Reverse Voltage 直流反向电压	$V_R$	100	V
RMS Reverse Voltage 反向电压均方根值	$V_{R(RMS)}$	70	V
Forward Rectified Current 正向整流电流	$I_F$	10	A
Peak Surge Current 峰值浪涌电流	$I_{FSM}$	150	A
Thermal Resistance J-A 结到环境热阻	$R_{\theta JA}$	60	$^{\circ}\text{C}/\text{W}$
Junction Temperature 结温	$T_J$	150	$^{\circ}\text{C}$
Storage Temperature 储藏温度	$T_{stg}$	-55to+150 $^{\circ}\text{C}$	$^{\circ}\text{C}$

■ **Electrical Characteristics 电特性**

( $T_A=25^{\circ}\text{C}$  unless otherwise noted 如无特殊说明, 温度为  $25^{\circ}\text{C}$ )

Characteristic 特性参数	Symbol 符号	Maximum 最大值	Unit 单位	Condition 条件
Forward Voltage 正向电压	$V_F$	0.7	V	$I_F=10\text{A}$
Reverse Current 反向电流	$I_R(25^{\circ}\text{C})$ $(125^{\circ}\text{C})$	0.1 20	mA	$V_R=V_{RRM}$
Diode Capacitance 二极管电容	$C_D$	400	pF	$V_R=4\text{V}$ , $f=1\text{MHz}$

■ Typical Characteristic Curve 典型特性曲线

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

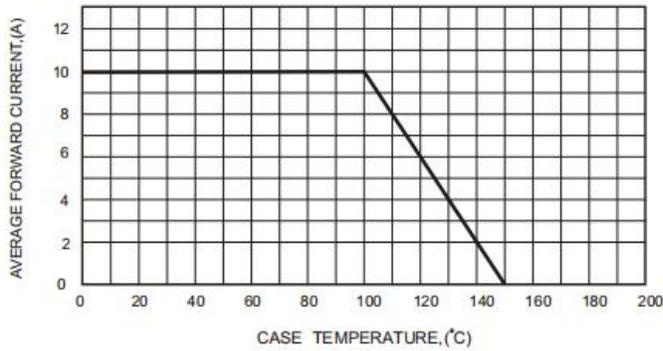


FIG.2-TYPICAL FORWARD CHARACTERISTICS

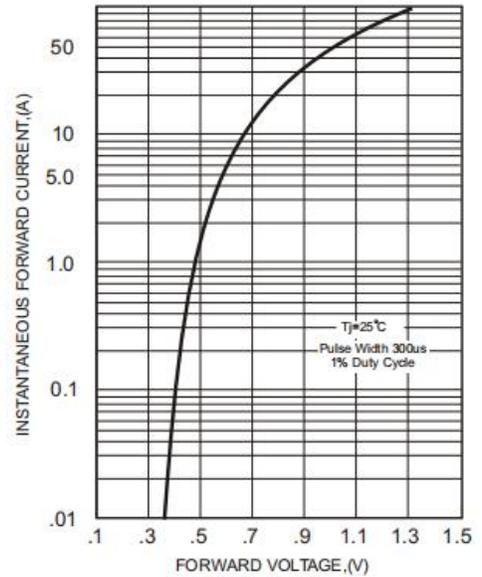


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

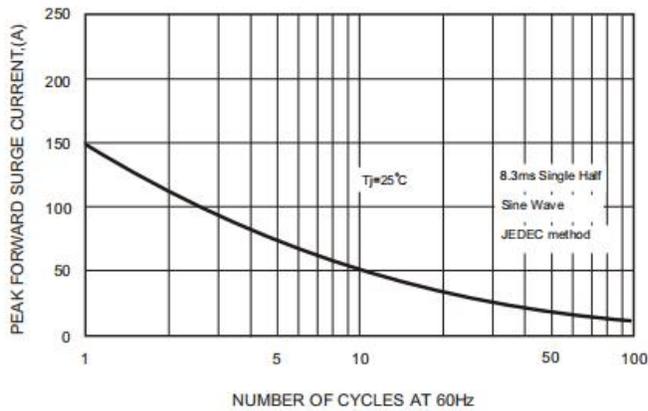


FIG.5 - TYPICAL REVERSE CHARACTERISTICS

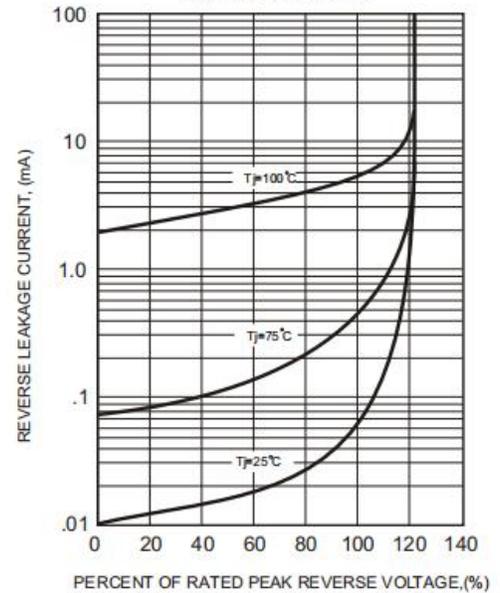
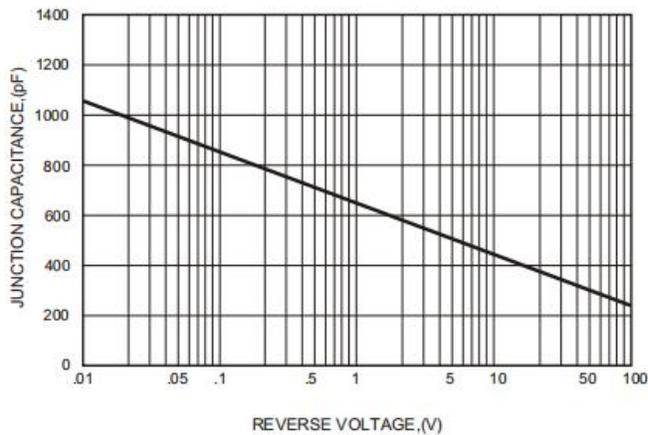


FIG.4-TYPICAL JUNCTION CAPACITANCE



■Dimension 外形封装尺寸

